

Use of a thin liquid film moving under the action of gas flow in a mini-channel for removing high heat fluxes

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Abstract. Intensively evaporating liquid films shear-driven in a mini- or micro-channel under the action of cocurrent gas flow are promising for the use in modern cooling systems of semiconductor devices. In this work, we investigated the influence of liquid and gas flow rates on the critical heat flux in a locally heated film of water, moving under the action of air flow in a mini-channel. In experiments a record value of critical heat flux of 870 W/cm² was reached. Heat spreading into the substrate and heat losses to the atmosphere in total do not exceed 25 % at heat fluxes above 400 W/cm². A comparison with the critical heat flux for water flow boiling in the channel shows that, for shear-driven liquid films the critical heat flux is almost an order of magnitude higher.

1 Introduction

The development of modern microelectronic equipment requires efficient cooling systems, as it is necessary to remove high heat fluxes, up to 1 kW/cm², from local areas of the processor [1]. Thin and ultrathin (less than 10 μm) liquid films moving under the action of forced gas flow in mini-channels are promising for the use in thermal control systems of modern semiconductor devices [2]. Works [3-5] established the basic laws of flow and crisis phenomena in the liquid film, moving under the action of gas flow in a horizontal mini-channel under local heating. First experiments with shear-driven liquid films showed that such films are less prone to thermocapillary rupture than the ones moving under the action of gravity. This is because the film rupture and the formation of dry spots can be controlled by the gas flow. As a result, the critical heat flux for shear-driven liquid films can be several times higher than that for falling liquid films. In works [6-7] it is found, that in two phase flows in rectangular channels the stratified flow sub-regime, when a very thin liquid film is moving along the channel walls under the action of cocurrent gas flow, can exist for the channel heights as small as 100 μm and less. Authors of [8] propose an efficient way of reduction of the viscous resistance in two-phase flows in micro-channels. All these studies confirm the prospects of using shear-driven liquid films for cooling of microsystems with high heat generation. The present paper presents new experimental data

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3 Results

This work studies the behavior of the liquid film, moving under the action of the gas at local heating, at different values of heat flux $q = 0-870 \text{ W/cm}^2$, Reynolds number of the liquid $Re_l = 8.5-113$ and superficial gas velocity in the channel $U_{sg} = 3.8-93 \text{ m/s}$. Figure 2 illustrates the process of film rupture with the increase in heat flux at $Re_l = 30$ and $U_{sg} = 30 \text{ m/s}$. At a certain threshold value of the heat flux the film disrupts with the formation of dry spots on the substrate. As a rule, initially dry areas are formed below the heater, along its side edges (Fig. 2a). Here we deal with thermocapillary film rupture, since dry patches initiate at temperatures well below the saturation temperature (the heater wall temperature is indicated at the capture of photos in Fig. 2). Thermocapillary tangential stresses at the film surface, induced by the dependence of the liquid surface tension on the temperature, and tangential stresses, induced by the flowing gas, are the main competitive forces at the gas-liquid interface. The film is thinnest along the lateral edges of the heater where temperature gradient at the film surface attains its maximum values. Film rupture is most likely to occur in this area. At a slightly higher heat flux, dry areas appear on the heater. With a further increase of the heat flux the heater is covered with metastable intensively evaporating thin liquid film with rapidly appearing and disappearing small dry spots (Fig. 2b). Upon reaching the critical heat flux, the heater suddenly dries up, and its temperature begins to increase sharply (Fig. 2c).

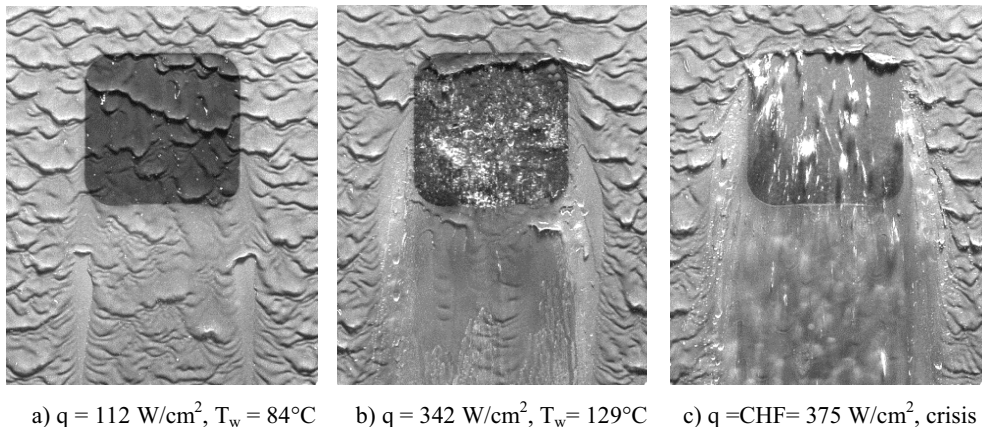


Fig. 2. Rupture and crisis in a water film moving under the action of the gas flow; the heater is $1 \times 1 \text{ cm}^2$, the channel height is 1.2 mm , $Re_l = 30$, $U_{sg} = 30 \text{ m/s}$, the flow is directed top-down.

Figure 3 shows data obtained on the critical heat flux depending on Reynolds number of liquid and superficial gas velocity. It is seen that with increasing Reynolds number of the liquid and superficial gas velocity, the critical heat flux increases. In experiments, a record value of critical heat flux 870 W/cm^2 was reached (Fig. 3, point $Re_l=113$, $U_{sg}=71 \text{ m/s}$). This critical heat flux for water film moving under the action of the gas flow was achieved at a mass flow rate of water $100 \text{ kg/m}^2\text{s}$. In this case, as shown in [9], the critical heat flux for subcooled water boiling in the mini-channel at the same mass flow rate of liquid (at atmospheric pressure and subcooling to the saturation temperature of 75 K) reaches a value 90 W/cm^2 (Fig. 3, line 7). According to [9], to reach a heat flux of 870 W/cm^2 at water flow boiling in the mini-channel the mass flow rate of the liquid shall be $5000 \text{ kg/m}^2\text{s}$, which 50 times exceeds the mass flow rate in our experiment. Fig. 3 also presents data on the critical heat flux for water pool boiling (formula of Kutateladze, line 5) as well as for water pool boiling at subcooling to the saturation temperature of 75 K (line 6) [10].

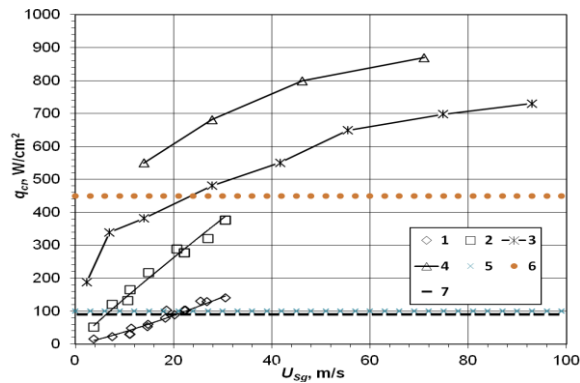


Fig. 3. Dependence of the critical heat flux on superficial gas velocity, U_{sg} , Reynolds number of the liquid Re_l , and the channel height H . 1 – $Re_l = 8.5$, $H = 1.2$ mm; 2 – $Re_l = 30$, $H = 1.2$ mm; 3 – $Re_l = 62$, $H = 1.0$ mm; 4 – $Re_l = 113$, $H = 1.0$ mm; 5 – water pool boiling (formula of Kutateladze $q_{cr} = 0.14r \sqrt{\rho_v} \sqrt[4]{\sigma g(\rho_l - \rho_v)}$, [10]); 6 – water pool boiling at subcooling to the saturation temperature of 75 K [10]; 7 – water flow boiling in a mini-channel for mass flow rate $100 \text{ kg/m}^2\text{s}$, at atmospheric pressure and subcooling to the saturation temperature of 75 K [9].

4 Conclusion

The critical heat flux for thin water films, moving under the friction of gas flow, is almost an order of magnitude higher than that for pool boiling and flow boiling in the channel. In the experiments, the record value of the critical heat flux of 870 W/cm^2 for thin film flows was reached. This confirms the prospects of using the shear-driven liquid films in modern cooling systems of semiconductor devices with high local heat generation. Total heat losses to the atmosphere and heat spreading into the substrate in our experiments do not to exceed 25 % at heat fluxes higher than 400 W/cm^2 .

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References

1. A. Bar-Cohen, P. Wang, ASME. J. Heat Transf. **134**, 051017 (2012)
2. O.A. Kabov, Yu.V. Lyulin, I.V. Marchuk and D.V. Zaitsev, Int. J. Heat Fluid Flow **28**, 103 (2007)
3. D.V. Zaitsev, D.A. Rodionov and O.A. Kabov, Tech. Phys. Lett. **35**, 680 (2009)
4. O.A. Kabov and D.V. Zaitsev, Multiphase Sci. Tech. **21**, 249 (2009)
5. O.A. Kabov, D.V. Zaitsev, V.V. Cheverda, A. Bar-Cohen, Exp. Therm. Fluid Sci. **35**, 825 (2011)
6. E.A. Chinnov, F.V. Ronshin, O.A. Kabov, Int. J. Aip. Conf. Proc. **80**, 57 (2016)
7. E.A. Chinnov, F.V. Ronshin, O.A. Kabov, Interfacial Phenomena and Heat Transfer **3**, 243 (2015)
8. E.Ya. Gatapova, V.S. Ajaev, O.A. Kabov, JETP Letters **101**, 160 (2015)
9. W. Zhang, T. Hibiki, K. Mishima, Y. Mi, Int. J. Heat Mass Tran. **49**, 1058 (2006)
10. S.S. Kutateladze, *Heat Transfer in Condensation and Boiling* (Mashgiz, Moscow, 1952)